# High Voltage, High Current Darlington Transistor Arrays

The seven NPN Darlington connected transistors in these arrays are well suited for driving lamps, relays, or printer hammers in a variety of industrial and consumer applications. Their high breakdown voltage and internal suppression diodes insure freedom from problems associated with inductive loads. Peak inrush currents to 500 mA permit them to drive incandescent lamps.

The ULx2003A with a 2.7 k $\Omega$  series input resistor is well suited for systems utilizing a 5.0 V TTL or CMOS Logic.

#### Features

• These are Pb-Free Devices

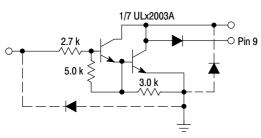


Figure 1. Representative Schematic Diagram

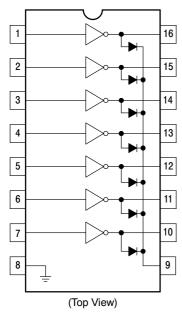
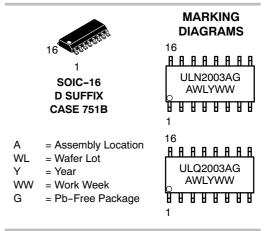


Figure 2. Pin Connections



## **ON Semiconductor®**

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## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
ULN2003ADR2G	SOIC-16 (Pb-Free)	2500 Tape & Reel
ULQ2003ADR2G	SOIC-16 (Pb-Free)	2500 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS (T<sub>A</sub> = 25°C, and rating apply to any one device in the package, unless otherwise noted.)

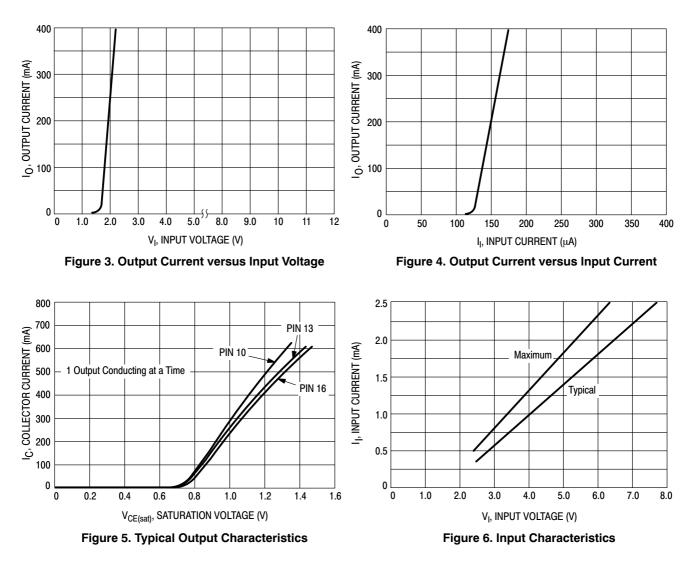
Rating	Symbol	Value	Unit
Output Voltage	Vo	50	V
Input Voltage	VI	30	V
Collector Current – Continuous	Ι <sub>C</sub>	500	mA
Base Current - Continuous	Ι <sub>Β</sub>	25	mA
Operating Ambient Temperature Range ULN2003A ULQ2003A	T <sub>A</sub>	-20 to +85 -40 to +85	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C
Junction Temperature	TJ	150	°C
Thermal Resistance, Junction-to-Ambient Case 751B, D Suffix	$R_{\theta JA}$	100	°C/W
Thermal Resistance, Junction-to-Case Case 751B, D Suffix	R <sub>θJC</sub>	20	°C/W
Electrostatic Discharge Sensitivity (ESD) Human Body Model (HBM) Machine Model (MM) Charged Device Model (CDM)	ESD	2000 400 1500	V

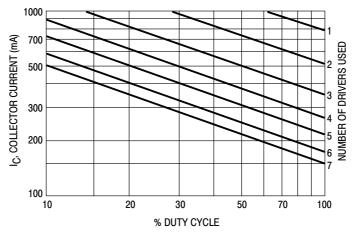
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

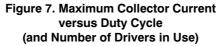
Characteristic		Min	Тур	Max	Unit
Output Leakage Current $(V_O = 50 \text{ V}, T_A = +85^{\circ}\text{C})$ $(V_O = 50 \text{ V}, T_A = +25^{\circ}\text{C})$	I <sub>CEX</sub>		- -	100 50	μΑ
Collector-Emitter Saturation Voltage ( $I_C = 350 \text{ mA}, I_B = 500 \mu \text{A}$ ) ( $I_C = 200 \text{ mA}, I_B = 350 \mu \text{A}$ ) ( $I_C = 100 \text{ mA}, I_B = 250 \mu \text{A}$ )	V <sub>CE(sat)</sub>	- - -	1.1 0.95 0.85	1.6 1.3 1.1	V
Input Current – On Condition (V <sub>I</sub> = 3.85 V)	I <sub>I(on)</sub>	-	0.93	1.35	mA
Input Voltage – On Condition $(V_{CE} = 2.0 \text{ V}, I_C = 200 \text{ mA})$ $(V_{CE} = 2.0 \text{ V}, I_C = 250 \text{ mA})$ $(V_{CE} = 2.0 \text{ V}, I_C = 300 \text{ mA})$	V <sub>I(on)</sub>	- - -	- - -	2.4 2.7 3.0	V
Input Current – Off Condition (I <sub>C</sub> = 500 $\mu$ A, T <sub>A</sub> = 85°C)	I <sub>I(off)</sub>	50	100	-	μΑ
DC Current Gain $(V_{CE} = 2.0 \text{ V}, I_C = 350 \text{ mA})$	h <sub>FE</sub>	1000	-	-	-
Input Capacitance	Cl	-	15	30	pF
Turn-On Delay Time (50% E <sub>I</sub> to 50% E <sub>O</sub> )	t <sub>on</sub>	-	0.25	1.0	μs
Turn-Off Delay Time (50% E <sub>I</sub> to 50% E <sub>O</sub> )	t <sub>off</sub>	-	0.25	1.0	μs
	I <sub>R</sub>		-	50 100	μΑ
Clamp Diode Forward Voltage (I <sub>F</sub> = 350 mA)	V <sub>F</sub>	-	1.5	2.0	V

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ , unless otherwise noted)

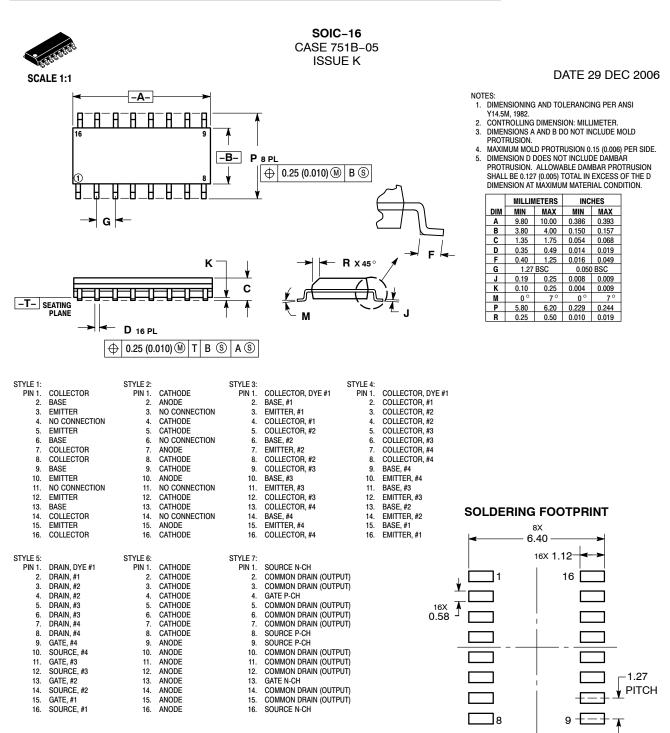
### TYPICAL PERFORMANCE CURVES – $T_A = 25^{\circ}C$











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